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this form)		
1. Your reference	SHG/P501127	
2. Patent application number (The Patent Office will fill in this part)	0300434.8	Fernan 1983
3. Full name, address and postcode of the or of each applicant (underline all surnames)	University College Cardiff Con No Box 491 S6 PALL RACE CARDIFF	sultants Ltd
Patents ADP number (if you know it)	7 680 3 111	
If the applicant is a corporate body, give the country/state of its incorporation	10198603009.	
4. Title of the invention	Semiconductor Optical Devi	ces
5. Name of your agent (If you have one)	URQUHART-DYKES & LOR	RD.
"Address for service" in the United Kingdon to which all correspondence should be sent (Including the postcode)	Three Trinity Court 21-27 Newport Road CARDIFF CF24 0AA	
Patents ADP number (If you know it)	1644025 .	Date of filing
6. If you are declaring priority from one or me earlier patent applications, give the country and the date of filing of the or of each of the earlier applications and (if you know it) the control of the country applications.	iese	v it) (day / month / year)
each application number 7. If this application is divided or otherwise derived from an earlier UK application, give the number and the filing date of the earlier application	Number of earlier application	Date of filing (day / month / year)
8. Is a statement of inventorship and of right to grant of a patent required in support of this request? (Answer Yes' if: a) any applicant named in part 3 is not an invent) there is an inventor who is not named as an applicant, or	ntor, or Yes	
c) any named applicant is a corporate body. See note (d))	ST AVAILABLE COPY	Patents Form 1/7

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Continuation sheets of this form

Description

3

Claim(s)

Abstract

Drawing (s)

10. If you are also filing any of the following, state how many against each item.

Priority documents

Translations of priority documents

Statement of inventorship and right to grant of a patent (Patents Form 7/77)

Request for preliminary examination and search (Patents Form 9/77)

Request for substantive examination (Patents Form 10/77)

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11.

I/We request the grant of a patent on the basis of this application.

Signature

Date

URQUHART-DYKES & LORD

12. Name and daytime telephone number of person to contact in the United Kingdom

Stewart Gibson

029 2048 7993

. Warning

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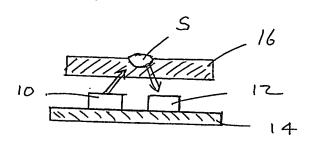


Figure 1

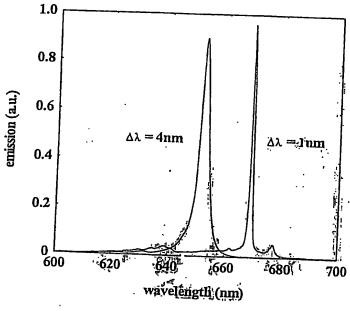


Figure 2

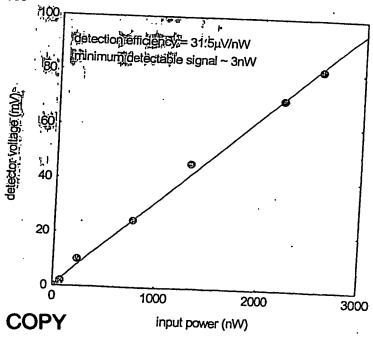


Figure 3

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Semiconductor Optical Devices

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The present invention relates to semiconductor optical devices, particularly but not solely for use in the field of bio-chemical or bio-medical analysis.

The use of optical techniques for the analysis of biological samples is a field of increasing importance, particularly in view of its potential for analysis at a molecular level. Various optical systems have been proposed hitherto: these systems have generally made use of a laser or other light emitter for directing light onto successive samples in an array, and a separate detector for picking up light from the individual samples; typically the samples have been marked with a flourescent dye, such that the incident light stimulates each sample to cause the emission of light of a different wavelength, which is picked up by the photodetector. Hitherto, such systems have been of large and complicated construction, for laboratory use. We have now devised a device of simple and small construction, which enables the device to be used in the field.

In accordance with the present invention, there is 20 provided a device for the analysis or testing of a biological sample, the device comprising a single light emitter for directing light onto a sample, and a single photodetector for receiving light from the sample.

The device is accordingly a single-channel device for use with a single sample (or a single sample at a time). The device may be constructed to a very small size and inexpensively, so that it can be used with ease in the field, and may indeed comprise a single use or disposable device.

The light emitter and photodetector may be mounted 30 side-by-side and arranged for the biological sample to be positioned over them. The device may comprise a carrier substrate for the sample, positioned permanently or removably over the light emitter and photodetector.

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Preferably the light emitter has a light emission peak at one wavelength and the photodetector has a light-absorbing peak at a different wavelength. In particular, the device may be arranged to detect fluorescent emission from the sample, stimulated by the light incident on it from the emitter.

The light emitter may comprise a vertical-cavity, surface emitting laser (VCSEL) or a resonant-cavity, light emitting diode (RCLED). The photodetector may comprise an identical device, having its emission peak at a different (longer) wavelength and used with a reverse bias, so as to act as a photodetector.

An embodiment of the present invention will now be described by way of example only and with reference to the accompanying drawings, in which;

15 FIGURE 1 is a schematic cross-section through a device in accordance with the invention;

FIGURE 2 is a graph showing the emission spectra of two light emitters used in the device of Figure 1; and

FIGURE 3 is a plot showing the detection performance of 20 one of the light emitters, used with reverse bias to act as a photodetector.

Referring to Figure 1 of the drawings, there is shown a device for the analysis of a biological sample, the device comprising a semiconductor light emitter 10 and a semiconductor photodetector 12 mounted side-by-side on a substrate 14. A sample-carrier 16 is positioned over the light emitter 10 and photodetector 12 and comprises a transparent substrate the upper surface of which is formed with a recess or well to receive the sample S to be analysed or tested. The substrate 30 16 may form a permanent part of the device, or it may be removable and replaceable.

The device is arranged so that the light emitted by the emitter 10 is incident on the sample S and the photodetector 12 picks up light returned from the sample S. In the example 35 shown in Figure 1, the light emitter 10 comprises a resonant-

cavity, light emitting diode (RCLED) with an emission peak at a wavelength of 650nm: the photodetector comprises an identical device except that it has an emission peak at 670nm and is used with a reverse voltage bias (so as to act as a photodetector 5 rather than light emitter). In use of the device, the sample S is marked with a fluorescent dye: accordingly, the light of 650nm wavelength which is incident on the sample, from the emitter 10, stimulates the sample to cause emission of light of the longer-wavelength, which is piked up by the 10 photodetector 12.

We have made and tested light emitters and photodetectors in the form of GaInP crystals having multiple-layer Bragg reflectors to produce circular beams perpendicular to their surfaces. By control of the thickness of these crystals, we formed two devices with emission peaks at 650nm and 670nm, respectively: the first such device is used as the emitter 10 and the second device, under reverse bias, as the photodetector 12.

Figure 2 shows the emission spectra of the two devices, 20 one having a peak at 650nm and the other a peak at 670nm.

Figure 3 shows the detected photovoltage, of the photodetector 12, in response to an optical signal. We found detection possible down to a noise floor of 3nW: for a typical fluorescent dye with a radiative lifetime of 5ns, this corresponds to the detection of the fluorescent emission from just 51 molecules, demonstrating the extremely high sensitivity of the photodetector.

It will be appreciated that the device described with reference to Figure 1 also comprises a battery power source for applying forward and reverse voltages to the emitter 10 and photodetector 12, respectively: the device further comprises a circuit for measuring the voltage or current output of the photodetector.